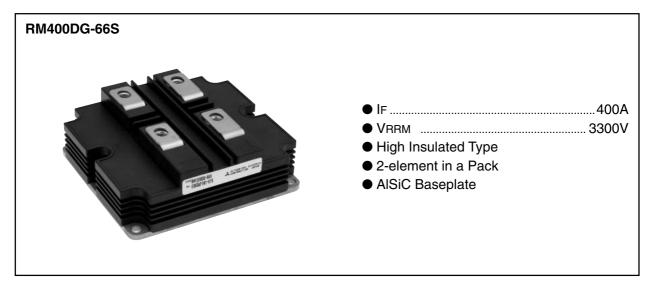
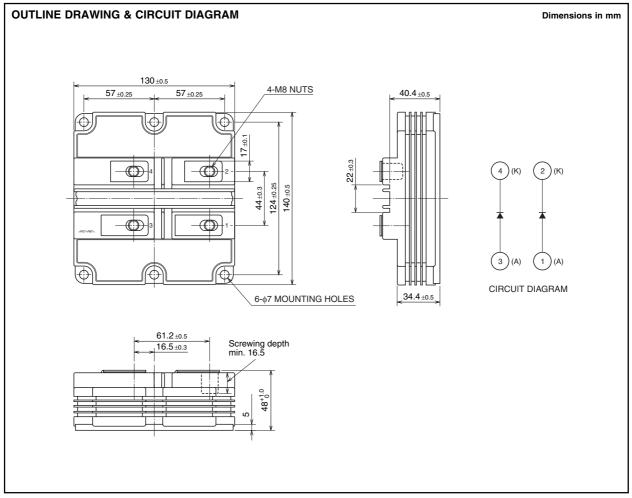
High Voltage Diode Module

HIGH POWER SWITCHING USE INSULATED TYPE



APPLICATION

Traction drives, High Reliability Converters / Inverters, DC choppers



High Voltage Diode Module



High Voltage Diode Module

HIGH POWER SWITCHING USE INSULATED TYPE

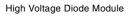
MAXIMUM RATINGS

Symbol	Item	Conditions	Ratings	Unit
VRRM	Repetitive peak reverse voltage	T _j = 25 °C	3300	V
VRSM	Non-repetitive peak reverse voltage	Tj = 25 °C	3300	V
VR(DC)	Reverse DC voltage	Tj = 25 °C	2200	V
lF	DC forward current	Tc = 25 °C	400	Α
IFSM	Surge forward current	Tj = 25 °C start, tw = 8.3 ms Half sign wave	3200	Α
l ² t	Current-squared, time integration	Tj = 25 °C start, tw = 8.3 ms Half sign wave	42.7	kA ² s
Viso	Isolation voltage	Charged part to the baseplate RMS sinusoidal, 60Hz 1min.	10200	٧
Ve	Partial discharge extinction voltage	RMS sinusoidal, 60Hz, QPD ≤ 10PC	5100	V
Tj	Junction temperature	_	-40 ~ +150	°C
Тор	Operating temperature	_	− 40 ~ +125	°C
Tstg	Storage temperature	_	-40 ~ +125	°C

ELECTRICAL CHARACTERISTICS

Cumbal	Item Conditions			Limits			Unit
Symbol	Item	Conditions		Min	Тур	Max	Unit
IRRM	Repetitive reverse current	$V_{RM} = V_{RRM}$ $T_j = 25 ^{\circ}C$ $T_j = 125 ^{\circ}C$	Tj = 25 °C	_	1	2	mA
			Tj = 125 °C	_	1	10	
VFM	Forward voltage (Note 1)	I= 400 A	Tj = 25 °C	_	2.80	_	V
		IF = 400 A	Tj = 125 °C	_	2.70	_	
trr	Reverse recovery time	VR = 1650 V, IF = 400 A di/dt = -1350 A/μs Ls=100nH, Tj = 125 °C		_	1.0	_	μs
Irr	Reverse recovery current			_	530	_	Α
Qrr	Reverse recovery charge			_	270	_	μC
Erec	Reverse recovery energy (Note 2)			_	0.3	_	J/P

Note 1. It doesn't include the voltage drop by internal lead resistance. 2. Erec is the integral of 0.1VRx0.1Irrxdt.





HIGH POWER SWITCHING USE INSULATED TYPE

High Voltage Diode Module

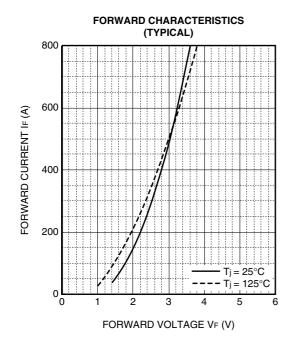
THERMAL CHARACTERISTICS

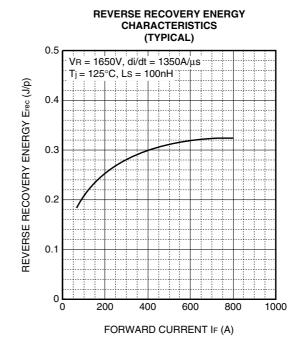
Symbol	Item	Conditions	Limits		Linit	
		Conditions	Min	Тур	Max	Unit
Rth(j-c)	Thermal resistance	Junction to case (per 1/2 module)	_	_	54.0	K/kW
Rth(c-f)	Contact thermal resistance	Case to Fin, λgrease = 1W/m·K D(c-f)=100μm, (per 1/2 module)		48.0	_	K/kW

MECHANICAL CHARACTERISTICS

Symbol	Item	Conditions	Limits			Limit
		Conditions	Min	Тур	Max	Unit
Mt	Mounting torque	M8: Main terminals screw	7.0	_	15.0	N⋅m
Ms		M6: Mounting screw	3.0	_	6.0	N⋅m
m	Mass	_	_	1.0	_	kg
CTI	Comparative tracking index	_	600	_	_	_
Da	Clearance	_	26	_	_	mm
Ds	Creepage distance	_	56	_	_	mm
LP CE	Internal inductance	_	_	44	_	nΗ
RCC'+EE'	Internal lead resistance	Tc = 25 °C	_	0.27	_	mΩ

PERFORMANCE CURVES



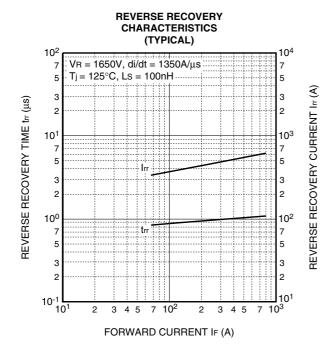


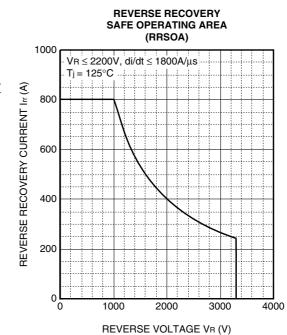
High Voltage Diode Module



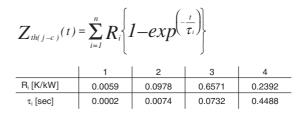
HIGH POWER SWITCHING USE INSULATED TYPE

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TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS 1.2 Rith(j-c) = 18K/kW 0.8 0.8 0.4 0.4 0.2 0.0 0.3 2 3 5710² 2 3 5710¹ 2 3 5710⁰ 2 3 5710¹ TIME (s)



High Voltage Diode Module



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